**Product data sheet** 

## 1. Product profile

## 1.1. General description

NPN medium power transistors in a medium power SOT223 (SC73) Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number	Package	NPN comlement	
	Nexperia	JEDEC	
BCP54T	SOT223	SC-73	BCP51T
BCP54-10T			BCP51-10T
BCP54-16T			BCP51-16T

### 1.2. Features and benefits

- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- · Three current gain selections
- · High power dissipation capability
- · AEC-Q101 qualified

## 1.3. Applications

- · Linear voltage regulators
- MOSFET drivers
- · High-side switches
- Power management
- Amplifiers

### 1.4. Quick reference data

Table 2. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	45	V
I <sub>C</sub>	collector current		-	-	1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	2	Α



## 45 V, 1 A NPN medium power transistors

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$h_{\text{FE}}$	DC current gain						
	BCP54T	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA	[1]	63	-	250	
	BCP54-10T		[1]	63	-	160	
	BCP54-16T		[1]	100	-	250	

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

## 2. Pinning information

## Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	С
2	С	collector		
3	E	emitter		в
4	С	collector	∃1 ∃2 ∃3	Ė
				sym123

# 3. Ordering information

## **Table 4. Ordering information**

Type number	Package					
	Name	Description	Version			
BCP54T	SC-73	plastic, surface-mounted package with increased heatsink;	SOT223			
BCP54-10T		4 leads				
BCP54-16T						

# 4. Marking

### Table 5. Marking

Type number	Marking code
BCP54T	BCP54T
BCP54-10T	P5410T
BCP54-16T	P5416T

#### 45 V, 1 A NPN medium power transistors

## 5. Limiting values

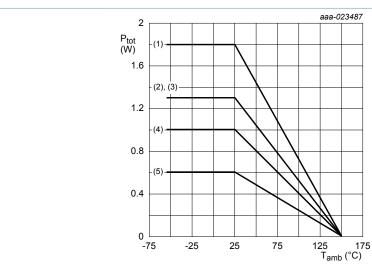
#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	45	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	45	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
I <sub>C</sub>	collector current			-	1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	2	Α
I <sub>B</sub>	base current			-	0.2	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	0.3	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.6	W
			[2]	-	1	W
			[3]	-	1.3	W
			[4]	-	1.3	W
			[5]	-	1.8	W
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.
- [5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm.<sup>2</sup>



- (1) FR4 PCB; 4-layer copper; 1 cm<sup>2</sup>
- (2) FR4 PCB; single-sided copper; 6 cm<sup>2</sup>
- (3) FR4 PCB; 4-layer copper; standard footprint
- (4) FR4 PCB; single-sided copper; 1 cm<sup>2</sup>
- (5) FR4 PCB; single-sided copper; standard footprint

#### Fig. 1. Power derating curves

BCP54T\_SER

## 45 V, 1 A NPN medium power transistors

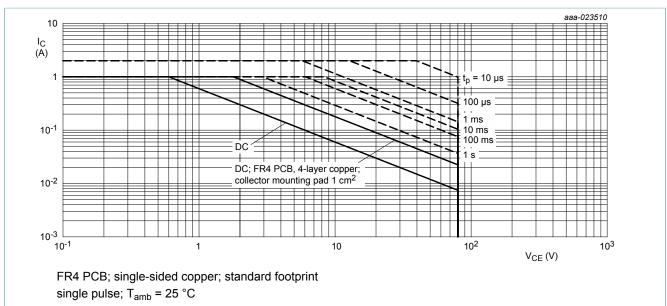


Fig. 2. Safe operating area; junction to ambient; continous and peak collector currents as a funtion of collecoremitter voltage

#### 45 V, 1 A NPN medium power transistors

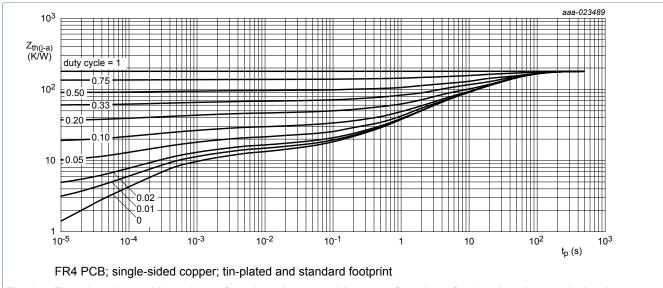
## 6. Thermal characteristics

#### **Table 7. Thermal characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

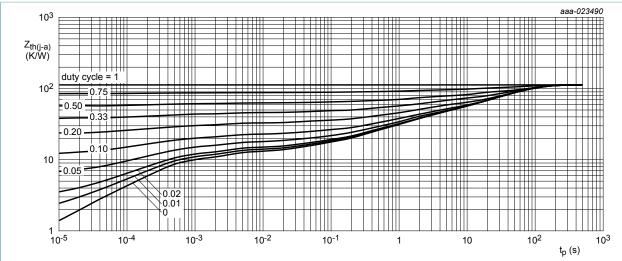
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal re	thermal resistance from junction to ambient	in free air	[1]	-	-	209	K/W
			[2]			125	K/W
			[3]			97	K/W
			[4]	-	-	97	K/W
			[5]	-	-	70	K/W
R <sub>(j-sp)</sub>	thermal resistance from junction to solder point			-	-	18	K/W

- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>. [3]
- Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint. [4]
- [5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



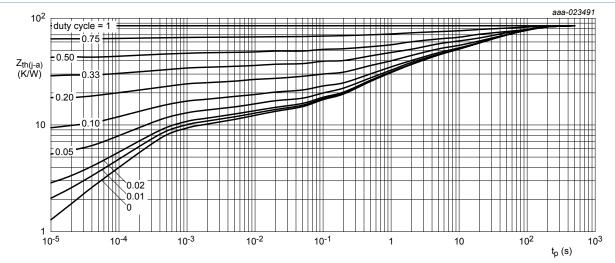
Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

#### 45 V, 1 A NPN medium power transistors



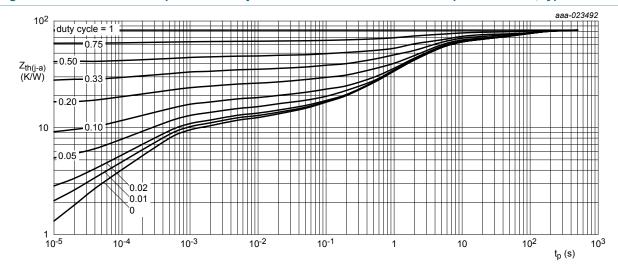
FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>

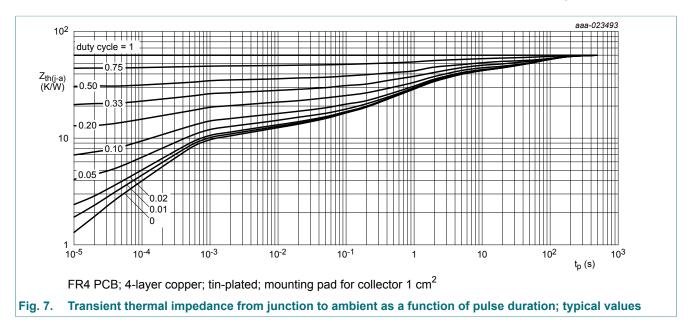
Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; 4-layer copper; tin-plated and standard footprint

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 45 V, 1 A NPN medium power transistors



## 7. Characteristics

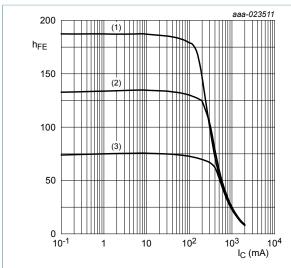
#### **Table 8. Characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 A		45	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = 2 mA; I <sub>E</sub> = 0 A		45	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I <sub>E</sub> = 100 μA; I <sub>C</sub> = 0 A		5	-	-	V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A		-	-	100	nA
	cut-off current	$V_{CB} = 30 \text{ V}; I_{E} = 0 \text{ A}; T_{j} = 150 \text{ °C}$		-	-	10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A		-	-	100	nA
h <sub>FE</sub> DC current gain					_	'	
	BCP54T, -10T, -16T	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA		63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA	[1]	40	-	-	
	BCP54T	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA	[1]	63	-	250	
	BCP54-10T	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA	[1]	63	-	160	
	BCP54-16T	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA	[1]	100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA	[1]	-	-	500	mV
$V_{BE}$	base-emitter voltage	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA	[1]	-	-	1	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz		100	155	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	4.5	-	pF

[1] pulsed;  $t_0 \le 300 \,\mu s$ ;  $\delta \le 0.02$ 

### 45 V, 1 A NPN medium power transistors



$$V_{CE} = 2 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. DC current gain as a function of collector current; typical values

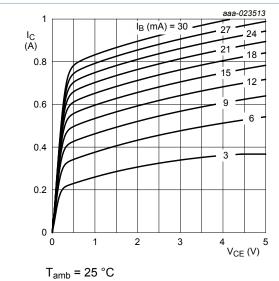
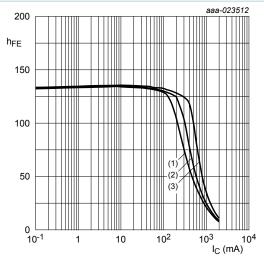


Fig. 10. Collector current as a function of collectoremitter voltage; typical values



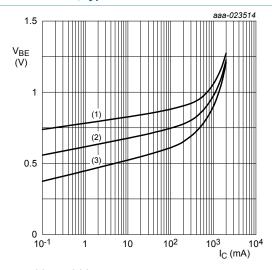
$$T_{amb} = 25 \, ^{\circ}C$$

(1) 
$$V_{CE} = 1 V$$

(2) 
$$V_{CE} = 2 V$$

(3) 
$$V_{CE} = 5 V$$

Fig. 9. DC current gain as a function of collector current; typical values



$$V_{CE} = 2 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

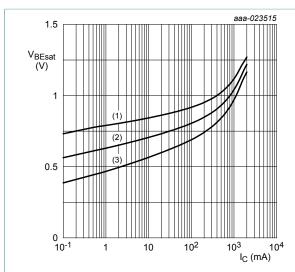
(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb}$$
 = 100 °C

Fig. 11. Base-emitter voltage as a function of collector current; typical values

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### 45 V, 1 A NPN medium power transistors



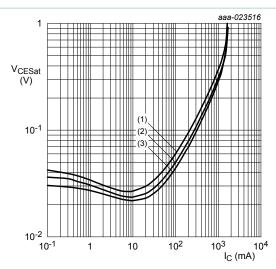
$$I_C/I_B = 10$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 12. Base-emitter saturation voltage as a function of Fig. 13. Collector-emitter saturation voltage as a collector current; typical values



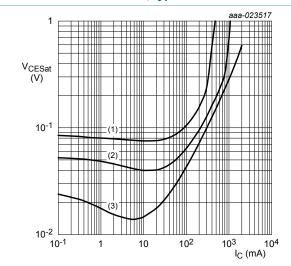
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb}$$
 = -55 °C

function of collector current; typical values



$$T_{amb}$$
 = 25 °C

(1) 
$$I_C/I_B = 50$$

(2) 
$$I_C/I_B = 20$$

(3) 
$$I_C/I_B = 5$$

Fig. 14. Collector-emitter saturation voltage as a function of collector current; typical values

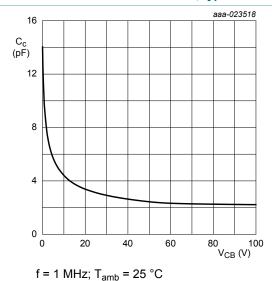
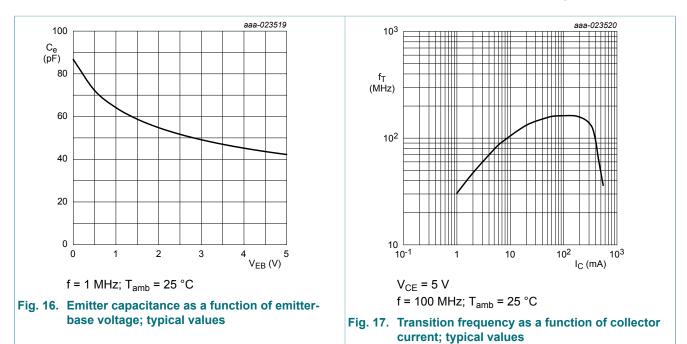


Fig. 15. Collector capacitance as a function of collector-

base voltage; typical values

#### 45 V, 1 A NPN medium power transistors

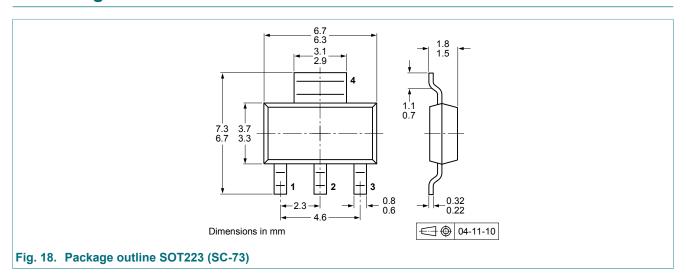


## 8. Test information

## 8.1. Quality information

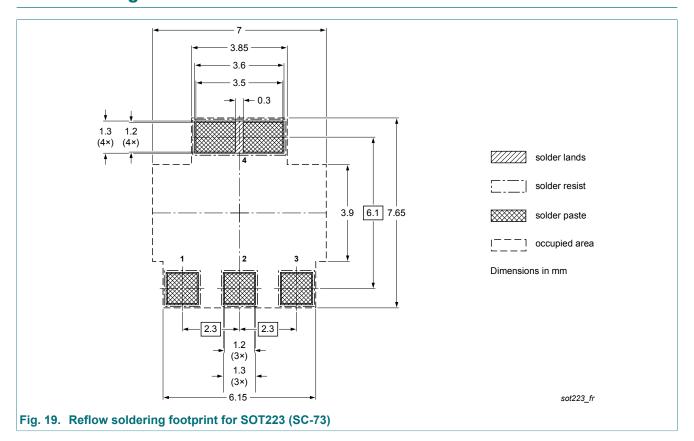
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

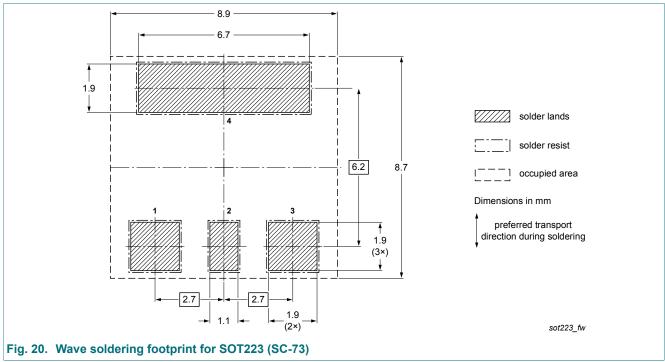
# 9. Package outline



### 45 V, 1 A NPN medium power transistors

# 10. Soldering





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45 V, 1 A NPN medium power transistors

# 11. Revision history

## Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCP54T_SER v.1	20190429	Product data sheet	-	-

# 45 V, 1 A NPN medium power transistors

## 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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## 45 V, 1 A NPN medium power transistors

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